

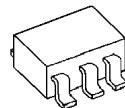
LOW DROPOUT VOLTAGE REGULATOR

■ GENERAL DESCRIPTION

The NJM2870 is low dropout voltage regulator designed for cellular phone application.

Advanced Bipolar technology achieves low noise, high ripple rejection and low quiescent current.

■ PACKAGE OUTLINE

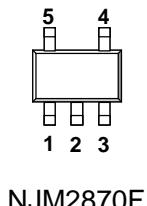


NJM2870F

■ FEATURES

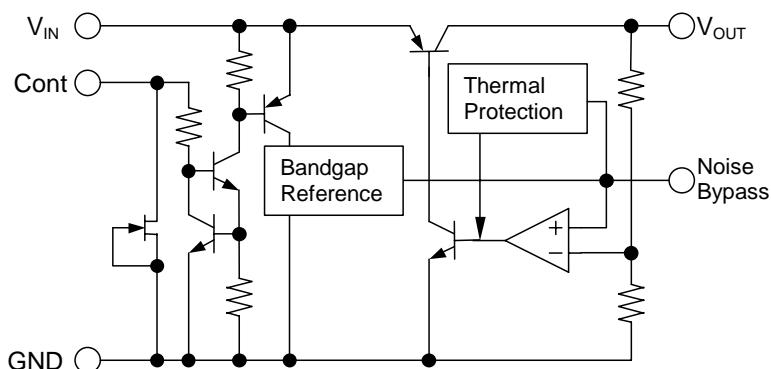
- High Ripple Rejection $56\text{dB} \leq RR$ ($\text{DC} < f < 60\text{kHz}$)
66dB typ. ($f=100\text{Hz}$)
60dB typ. ($f=1\text{kHz}$)
- Output Noise Voltage $V_{\text{no}}=30\mu\text{V}$ typ. ($C_p=0.01\mu\text{F}$)
- Output Current $I_o(\text{max.})=150\text{mA}$
- High Precision Output $V_o \pm 2\%$
- Low Dropout Voltage $\Delta V_{\text{DO}}=0.12\text{V}$ typ. ($I_o=60\text{mA}$, $V_o \geq 1.8\text{V}$)
- Input Voltage range +2~+14V ($V_o=1.5\text{V}$ Version)
- ON/OFF Control (Active High)
- Output capacitor with 4.7uF ceramic capacitor
- Internal Short Circuit Current Limit
- Internal Thermal Overload Protection
- Bipolar Technology
- Package Outline SOT-23-5

■ PIN CONFIGURATION



- PIN FUNCTION
 1. CONTROL (Active High)
 2. GND
 3. NOISE BYPASS
 4. V_{OUT}
 5. V_{IN}

■ EQUIVALENT CIRCUIT



■ ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

PARAMETER	SYMBOL	RATINGS		UNIT
Input Voltage	V _{IN}	+14		V
Control Voltage	V _{CONT}	+14(*1)		V
Power Dissipation	P _D	SOT-23-5	350(*2) 200(*3)	mW
Operating Temperature	Topr	-40 ~ +85		°C
Storage Temperature	Tstg	-40 ~ +125		°C

(*1) When input voltage is less than +14V, the absolute maximum control voltage is equal to the input voltage.

(*2): Mounted on glass epoxy board based on EIA/JEDEC. (114.3x76.2x1.6mm: 2Layers)

(*3): Device itself.

■ ELECTRICAL CHARACTERISTICS (V_{IN}=Vo+1V, C_{IN}=0.1μF, Co=4.7μF, Cp=0.01μF, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo	I _O =30mA	-2%	—	+2%	V
Quiescent Current	I _Q	I _O =0mA, expect I _{cont}	—	200	300	μA
Quiescent Current at Control OFF	I _{Q(OFF)}	V _{CONT} =0V	—	—	100	nA
Output Current	I _O	Vo-0.3V	150	200	—	mA
Line Regulation	ΔVo/ΔV _{IN}	V _{IN} =Vo+1V ~ Vo+6V, I _O =30mA	—	—	0.10	%/V
Load Regulation	ΔVo/ΔI _O	I _O =0 ~ 100mA	—	—	0.03	%/mA
Dropout Voltage	ΔV _{I-O}	I _O =60mA	—	0.12	0.2	V
Ripple Rejection	RR	ein=200mVrms, f=1kHz, I _O =10mA V _{IN} =Vo+2V, Vo=3V Version	—	60	—	dB
Average Temperature Coefficient of Output Voltage	ΔVo/ΔTa	Ta=0~85°C, I _O =10mA, Vo=3V Version	—	0.2	—	mV/°C
Output Noise Voltage	V _{NO}	f=10Hz~80kHz, I _O =10mA, Vo=3V Version	—	30	—	μVrms
Control Voltage for ON-state	V _{CONT(ON)}		1.6	—	—	V
Control Voltage for OFF-state	V _{CONT(OFF)}		—	—	0.6	V

The above specification is a common specification for all output voltages.

Therefore, it may be different from the individual specification for a specific output voltage.

■ ELECTRICAL CHARACTERISTICS

(Vo=1.5V Version, V_{IN}=2.4V, C_{IN}=0.1μF, Co=4.7μF, Cp=0.01μF, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo	I _O =30mA	-2%	—	+2%	V
Quiescent Current	I _Q	I _O =0mA, expect I _{cont}	—	200	300	μA
Quiescent Current at Control OFF	I _{Q(OFF)}	V _{CONT} =0V	—	—	100	nA
Output Current	I _O	Vo-0.3V	150	200	—	mA
Line Regulation	ΔVo/ΔV _{IN}	V _{IN} =Vo+1V ~ Vo+6V, I _O =30mA	—	—	0.10	%/V
Load Regulation	ΔVo/ΔI _O	I _O =0 ~ 100mA	—	—	0.03	%/mA
Ripple Rejection	RR	ein=200mVrms, f=1kHz, I _O =10mA V _{IN} =Vo+2V	—	64	—	dB
Average Temperature Coefficient of Output Voltage	ΔVo/ΔTa	Ta=0~85°C, I _O =10mA	—	0.13	—	mV/°C
Output Noise Voltage	V _{NO}	f=10Hz~80kHz, I _O =10mA,	—	15	—	μVrms
Control Voltage for ON-state	V _{CONT(ON)}		1.6	—	—	V
Control Voltage for OFF-state	V _{CONT(OFF)}		—	—	0.6	V

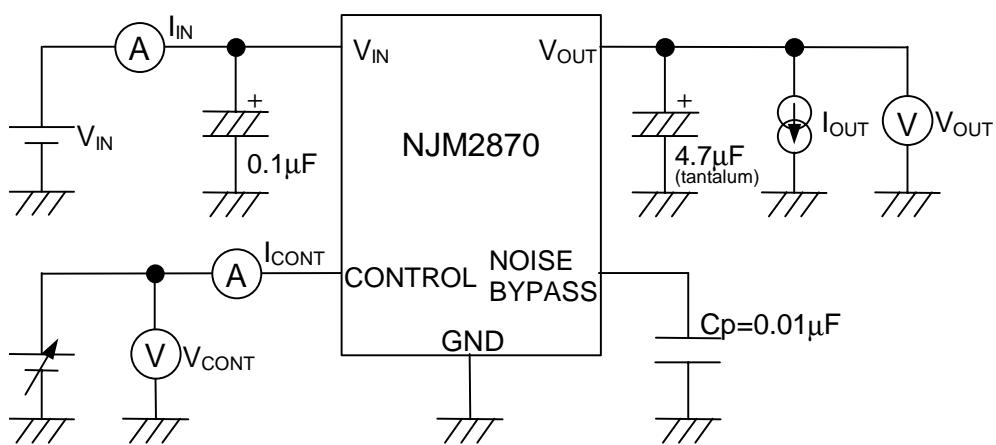
■ OUTPUT VOLTAGE RANK LIST

Device Name	V_{OUT}
NJM2870F15	1.5V
NJM2870F18	1.8V
NJM2870F19	1.9V
NJM2870F02	2.0V
NJM2870F21	2.1V
NJM2870F23	2.3V
NJM2870F24	2.4V
NJM2870F25	2.5V
NJM2870F26	2.6V

Device Name	V_{OUT}
NJM2870F27	2.7V
NJM2870F28	2.8V
NJM2870F285	2.85V
NJM2870F29	2.9V
NJM2870F03	3.0V
NJM2870F31	3.1V
NJM2870F32	3.2V
NJM2870F33	3.3V
NJM2870F34	3.4V

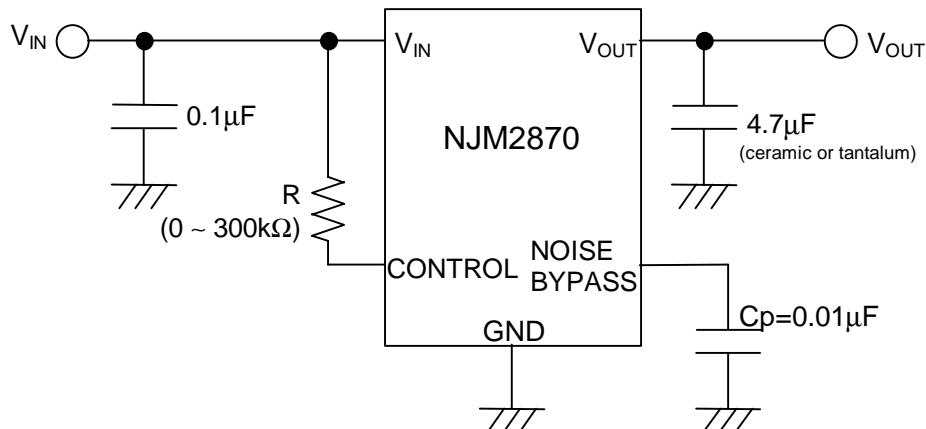
Device Name	V_{OUT}
NJM2870F35	3.5V
NJM2870F36	3.6V
NJM2870F38	3.8V
NJM2870F04	4.0V
NJM2870F45	4.5V
NJM2870F46	4.6V
NJM2870F47	4.7V
NJM2870F48	4.8V
NJM2870F05	5.0V

■ TEST CIRCUIT



■ TYPICAL APPLICATION

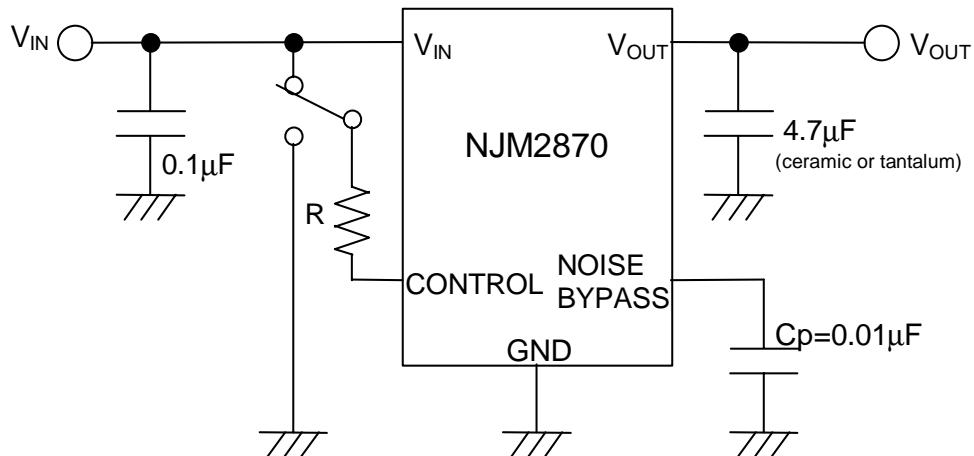
- ① In case that ON/OFF Control is not required:



Connect control terminal to V_{IN} terminal

The quiescent current can be reduced by using a resistance "R". Instead, it increases the minimum operating voltage. For further information, please refer to Figure "Output Voltage vs. Control Voltage".

- ② In use of ON/OFF CONTROL:



State of control terminal:

- "H" → output is enabled.
- "L" or "open" → output is disabled.

*Noise bypass Capacitance Cp

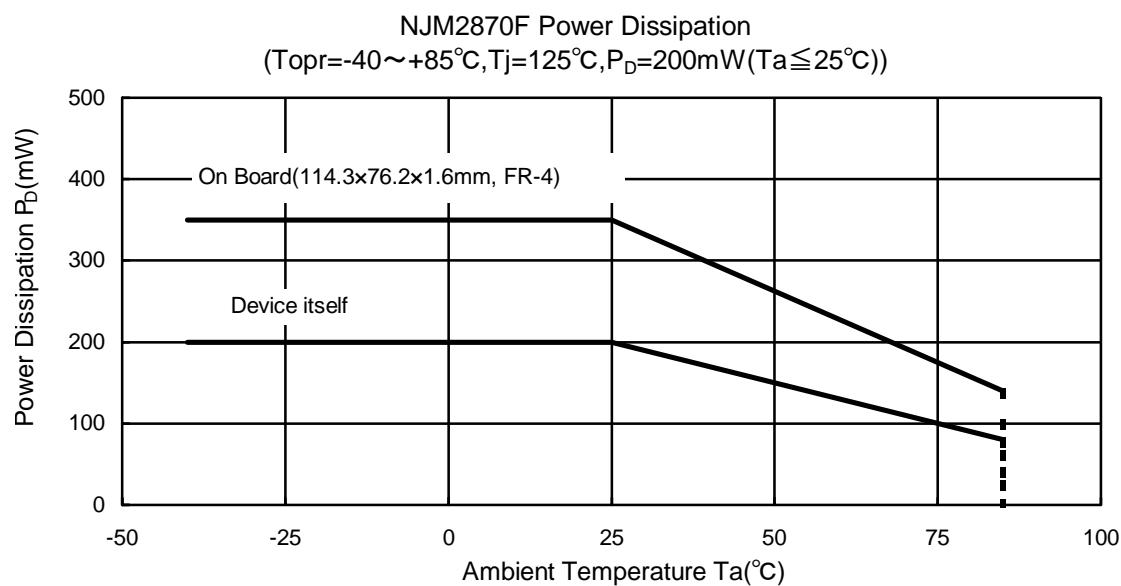
Noise bypass capacitance Cp reduces noise generated by band-gap reference circuit.

Noise level and ripple rejection will be improved when larger Cp is used.

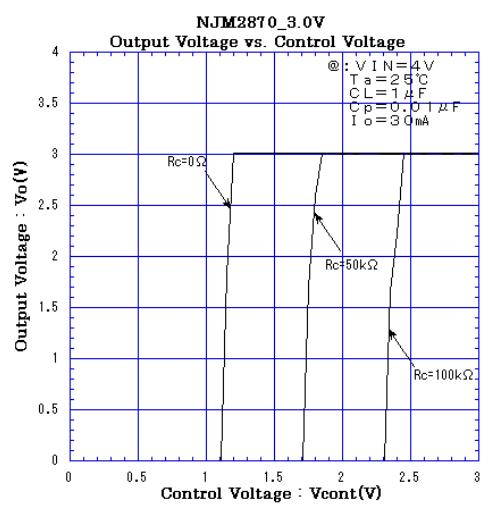
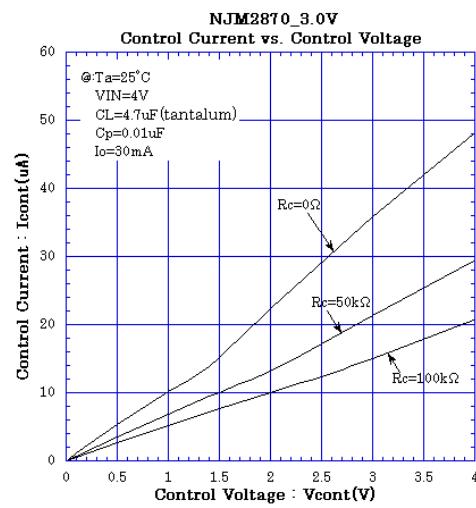
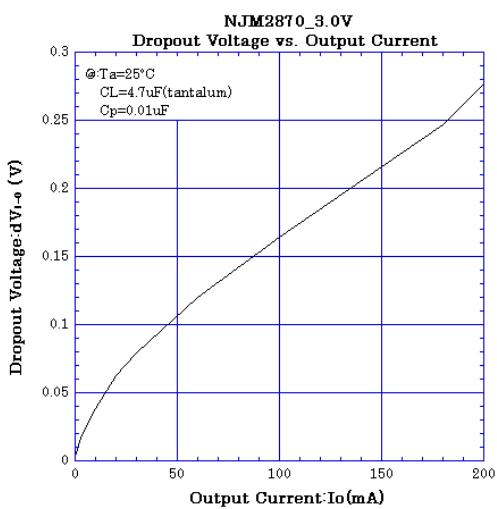
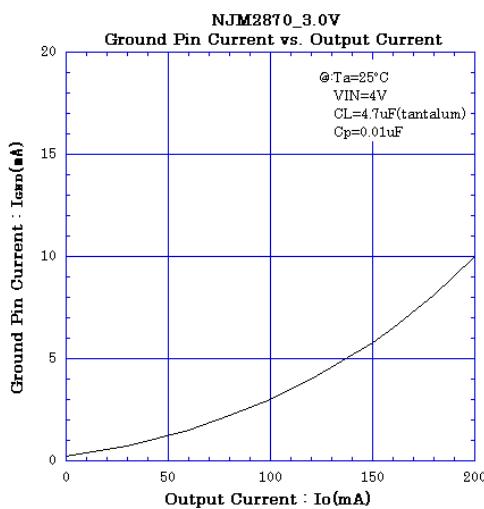
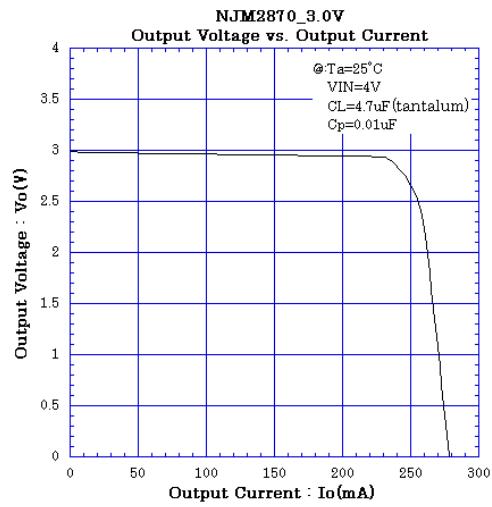
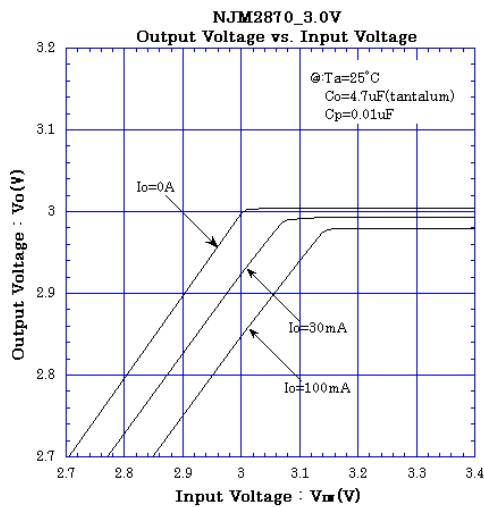
Use of smaller Cp value may cause oscillation.

Use the Cp value of 0.01uF greater to avoid the problem.

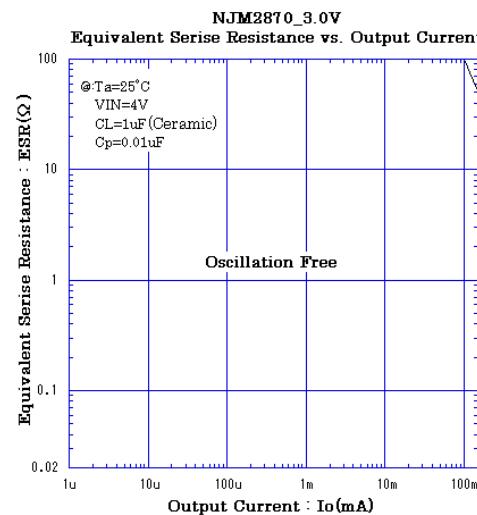
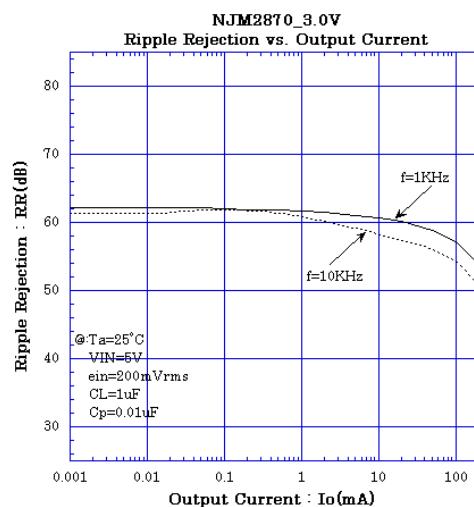
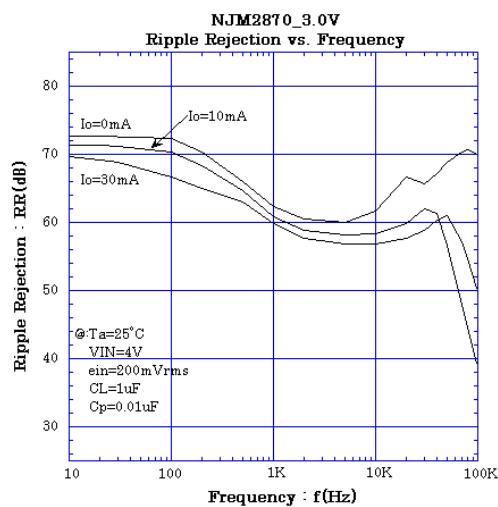
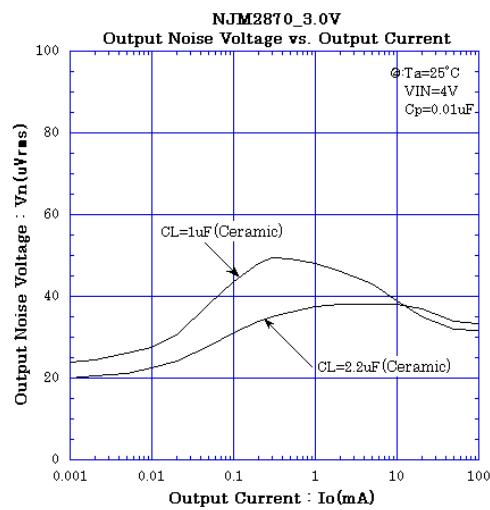
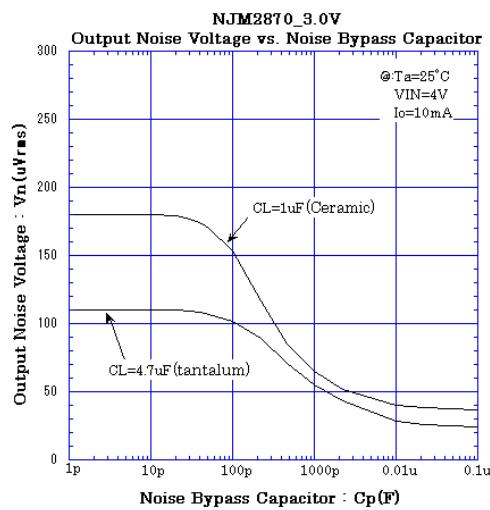
■ POWER DISSIPATION vs. AMBIENT TEMPERATURE



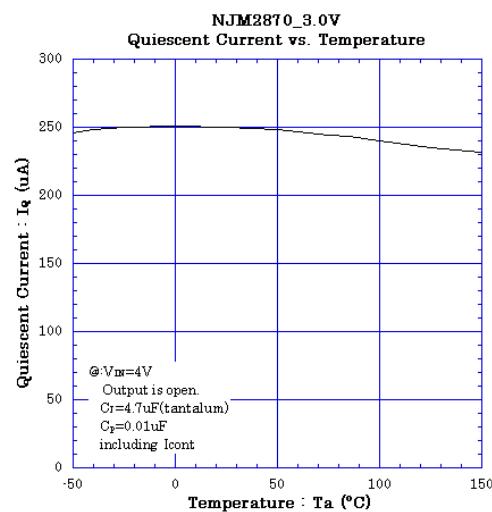
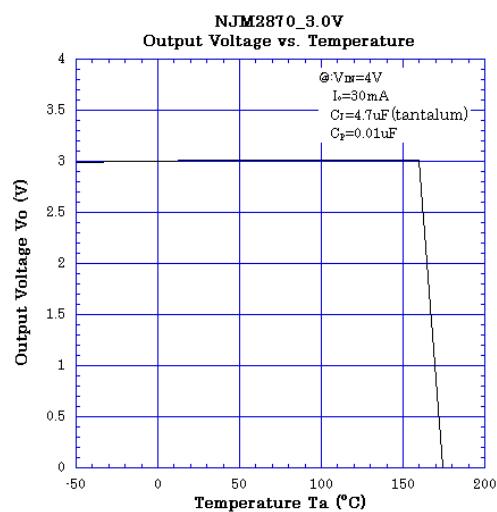
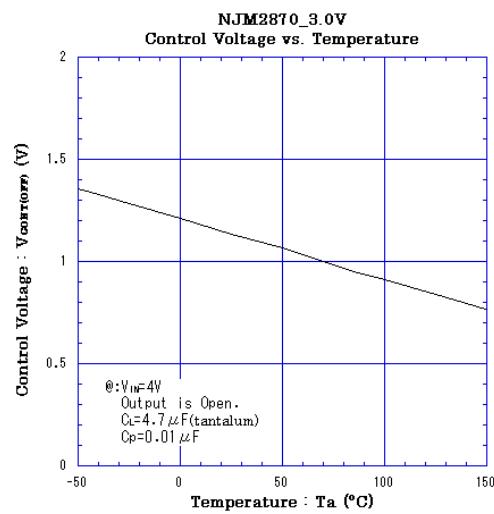
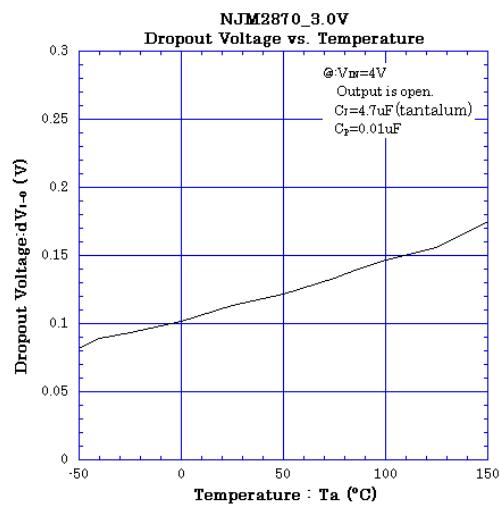
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS



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